

10/802799

Classification: 365/156.000

Status: 93 - NOTICE OF ALLOWANCE MAILED -- APPLICATION RECEIVED IN OFFICE OF PUBLICATIONS  
Title: SEMICONDUCTOR MEMORY INCLUDING STATIC RANDOM ACCESS MEMORY FORMED OF FINFET

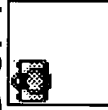
Examiner: NGUYEN, DANG

Inventor: WATANABE, TAKESHI, et al

GAU: 2824

Bib Data report

**Application Title: SEMICONDUCTOR MEMORY INCLUDING STATIC RANDOM ACCESS  
MEMORY FORMED OF FINFET**



Application Num:

(in phx) 10/802799

Filing Date: 03/18/2004

Effective

Filing: 03/18/2004

(Location History)

(Foreign/Continuity Data)

Status: 93/NOTICE OF ALLOWANCE MAILED -- APPLICATION RECEIVED IN OFFICE OF  
PUBLICATIONS Status Date: 08/10/2005

Patent Number: Not Issued

Issue Date: N/A

Date of Abandonment: N/A

Confirmation Number: 5098

PALM Location:

Examiner: 80030

NGUYEN, DANG (Assignment Data) Group Art Unit 2824

Class/Subclass: 365/156.000

State or Country: JAPAN Sheets/Drawing: 5 Total Claims: 18 Independent Claims: 3

Inventors:

Last name, First name:

City:

Country or State: